

Current-voltage characteristics and the zero-resistance state in a 2DEG

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We study the current-voltage characteristics (*CVC*) of two-dimensional electron gases (2DEG) with microwave induced negative conductance in a magnetic field. We show that due to the Hall effect, strictly speaking there is no distinction between N- and S-shaped *CVC*s. Instead the observed *CVC* depends on the experimental setup with, e.g., an N-shaped *CVC* in a Corbino disc geometry corresponding to an S-shaped *CVC* in a Hall bar geometry in a strong magnetic field. We argue that instabilities of homogeneous states in regions of negative differential conductivity lead to the observation of zero resistance in Hall bars and zero conductance in Corbino discs and we discuss the structure of current and electric field domains.

An interesting effect has been observed in recent papers [1, 2]: the resistance of a two-dimensional electron gas (2DEG) subjected to microwave irradiation drops to zero in some interval of an applied magnetic field B . This zero resistance state (ZRS) is achieved at low magnetic fields where at the measurement temperatures Shubnikov-de Haas oscillations are weak. Possible mechanisms for this phenomenon are discussed in a number of papers [3, 4, 5, 6, 7, 8, 9]. It was shown in Refs. [4, 7, 8] that in the presence of irradiation and a magnetic field the conductivity σ_{xx} may become negative in a weak electric field E_x . In addition, using a simple model, the authors of Ref. [7] have calculated the current-voltage characteristic $I(V)$ of an irradiated system with a density-of-states periodic in energy ε . They have demonstrated that not only regions with negative conductance G , but also regions with positive G , may have negative differential conductance $G_d = dI/dV$ on the current-voltage characteristic (*CVC*) curve. According to Ref. [7] the $I(V)$ curve is N-shaped (or to be more exact it can be regarded as a chain of the N-shaped *CVC*s), similar to the one shown in Fig. 1. This means that three voltages correspond to one current. While the authors of Ref. [7] do not show in detail how the ZRS arises in their approach, a phenomenological model for the ZRS was proposed in Ref. [5]. Here, the authors assumed that the resistivity ρ_{xx} depends on the current density j in such a way that the dependence of electric field on current density, $E_x = \rho_{xx}(j)j_x$, is N-shaped. This means that the inverse dependence $j_x(E_x)$ is S-shaped (three currents correspond to one voltage, cf. Fig. 3). It was shown that the states corresponding to the part of the *CVC* with negative differential conductance are unstable. The authors assumed that a stratification of the uniform current density occurs as a result of this instability and two current domains with opposite current directions arise in the Hall bar. With increasing total current I_x the relative width of the two domains changes and the electric field E_x remains zero, that is a ZRS is established in the system.

We note that the results presented in Refs. [4, 5, 7, 8]

are not completely new. Many years ago the absolute negative conductance has been predicted in Refs. [10, 11, 12] (2 and 3DEG in a strong magnetic field under irradiation) and in [13] (a superlattice under irradiation). The instability of systems with N- or S-shaped *CVC* in the absence of a magnetic field and the possible types of the electric field or current domains arising as a result of this instability also has been studied three decades ago (see, for example, the review [14] and references therein). The instability of a system with S-shaped *CVC* in a magnetic field was studied in Ref. [15]. As a result of the instability of a homogeneous state, in systems with N-shaped *CVC*, domains of constant electric field arise whereas in systems with S-shaped *CVC* domains with constant current density appear. In the absence of a magnetic field it was shown that a wide domain of constant electric field leads to a horizontal line on the *CVC* (zero differential conductance state) whereas a wide current domain in the sample leads to the appearance of a vertical line on the *CVC* (zero differential resistance state) [14, 16].

Currently, there does not appear to be a consensus as to what kind of *CVC*, N- or S-shaped, will lead to the ZRS in the presence of a magnetic field. In the present paper we address this issue and analyse the form of the *CVC* as well as the type of domains in different experimental setups. We consider a 2DEG in a magnetic field B and assume that the conductivity $\sigma_{xx} \equiv \sigma$ depends on the electric field E and the Hall conductivity $\sigma_{xy} \equiv \sigma_H$ is independent of the electric field E . We are not going to analyse the origin of this type of non-linear behavior and just note that this kind of dependence is discussed in Ref. [7]. In a two-dimensional system, the electric field E has two components $E_{x,y}$ so that the conductivity σ depends on $E = (E_x^2 + E_y^2)^{1/2}$. If one of two components vanishes identically (for example $E_y = 0$), as it happens in measurements on the Corbino disc, then $j_x = \sigma(E_x)E_x$. We assume that the $\sigma(E_x)$ dependence corresponds to an N-shaped *CVC* (see Fig. 1). We will show that the form of the *CVC* in experiments on a Hall bar depends strongly on the magnetic field, becoming S-shaped in the limit of strong Hall effect: $\sigma_H \gg |\sigma|$. This

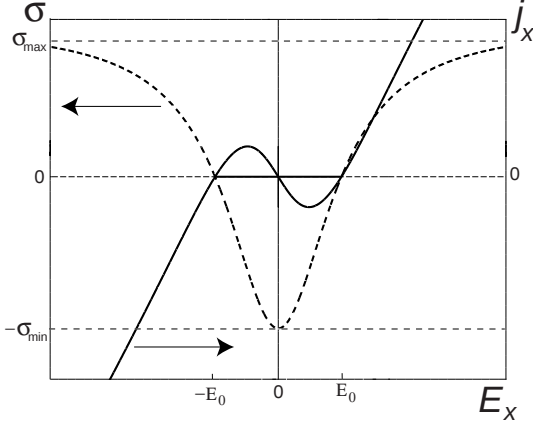


FIG. 1: Assumed N-shaped CVC (solid line) and the corresponding dependence of the conductivity σ on the electric field E_x (dashed line). Both the current component j_x and the conductivity σ are zero at $E_x = \pm E_0$. The solid horizontal line ($j_x = 0$, $|E_x| < E_0$) corresponds to a measurable part of the CVC in the Corbino disc measurements.

regime $\omega_c \tau_t \gg 1$, where ω_c is the cyclotron frequency and τ_t is the momentum relaxation time, is relevant to the experiments under consideration. We note in passing that in the experiments, due to the predominant forward scattering nature of the disorder, the single particle lifetime τ_s is much shorter than τ_t [1]. In the following, we will discuss the form of the CVC and the structure of non-homogeneous states (electric field and current domains) in different experimental setups.

We consider a 2DEG in a magnetic field assuming first that the current density j and the electric field E are homogeneous in the sample. The current density $j_{x,y}$ depends on the electric field $E_{x,y}$ via the components σ and σ_H of the conductivity tensor,

$$j_{x,y} = \sigma(E)E_{x,y} \pm \sigma_H E_{y,x}. \quad (1)$$

If the sample has the shape of a Corbino disc, the electric field E_y in the azimuthal direction is zero, and the CVC shown in Fig. 1 is N-shaped. If we consider a sample in the shape of a Hall bar, then in general both components $E_{x,y}$ are finite. However, the current component j_y in the Hall bar is zero and hence we can express the component E_y through E_x : $E_y = E_x \sigma_H / \sigma(E)$. Inserting it into the expression for the current density j_x , we get the dependence of j_x on E_x ,

$$j_x = \frac{(\sigma^2(E) + \sigma_H^2)}{\sigma(E)} E_x. \quad (2)$$

For the component E_x of the electric field we get

$$|E_x| = \frac{|\sigma(E)|}{\sqrt{\sigma^2(E) + \sigma_H^2}} E. \quad (3)$$

Eqs. (2) and (3) determine the form of the CVC for the Hall bar. We plot the resulting CVC in Figs. 2 and 3 for the case of low and high magnetic field, respectively. We see that in a weak field, $\sigma_{\min, \max} \gg \sigma_H$, the CVC for almost all currents follows the form of the $I(V)$ characteristic shown in Fig. 1. However at low currents, $j_x \approx \sigma_H E_0$, the shape of the CVC changes drastically. This kind of the CVC can not be assigned either to the N- or S-shaped types of the CVC. Associated with the loops is a change of the Hall angle from small values at large negative j_x to a value close to π near $j_x = E_x = 0$ and back to small values at large j_x .

With increasing magnetic field the form of the CVC changes and finally, at $\sigma_H \gtrsim \sigma_{\min, \max}$, is transformed into an S-shaped $I(V)$ characteristic (Fig. 3). The $I(V)$ curve crosses the y-axis at the currents $j_x = 0, \pm j_0$, where $j_0 = \sigma_H E_0$. The characteristic field E_{x1} at which $dj_x(E_x)/dE_x = \infty$ is determined by $E_x = E_{x1}(E_1)$, where E_1 satisfies the equation $E_1 d\sigma(E_1)/dE_1 = -\sigma(E_1)$ and is of the order of $E_{x1} = a E_0 \sigma_{\min} / \sigma_H$ ($a = 2/3^{3/2}$ for a parabolic dependence of $\sigma(E)$ on E at small E). The corresponding value of the current is $j_x(E_{x1}) = j_0 / \sqrt{3}$ in the same approximation. In the limit of high magnetic field, $\omega_c \tau_t \gg 1$, the Hall angle does not change appreciably and oscillates around $\pi/2$.

In order to check the applicability of this model to the experiments [1, 2], it would be interesting to measure the CVC in two configurations. If the CVC is measured on a Corbino disc, the $I(V)$ curve should have the form shown in Fig. 1, that is the N-shaped form. However due to instability of a homogeneous state, a horizontal line ($j_x = 0$) should be observed in the interval $-E_0 < E_x < E_0$ (zero conductance state). In principle one can also observe the part with negative absolute and differential conductance if short pulses of the voltage are applied to the sample. This method of measuring the CVC of a homogeneous sample was used in studies of the Gunn effect a long time ago (see the review [14] and references therein). The duration of the voltage pulses should be shorter than a characteristic time for the build-up of the electric field domains, but longer than the period of the ac field applied to the sample. In dc measurements the domains of the electric field $E_x(x)$ should appear as it happens for example in the Gunn effect. In the system under consideration the electric field has different direction in each domain. A variation of the total voltage leads to a change of the relative widths of the domains; the current remains negligible (zero conductance state). Due to the Hall effect, the electric field domains also carry current densities. Since the strength of the electric field is given by the critical field E_0 where the Hall angle is $\pi/2$, the associated currents always flow perpendicular to the direction of the electric field. Thus, in a magnetic field, current and electric field domains exist simultaneously.

If the CVC is measured on a Hall bar, it has the form shown in Fig. 3 with a vertical line in the interval

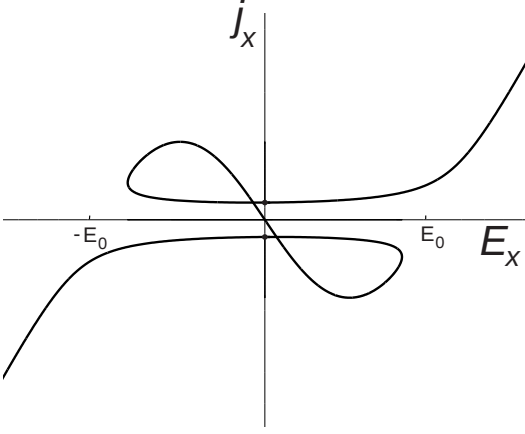


FIG. 2: The CVC in the case of a weak magnetic field. Here $\sigma_{min} = \sigma_{max} = 10\sigma_H$. The curve intersects the line $E_x = 0$ at the points $j_x = 0, \pm\sigma_H E_0$.

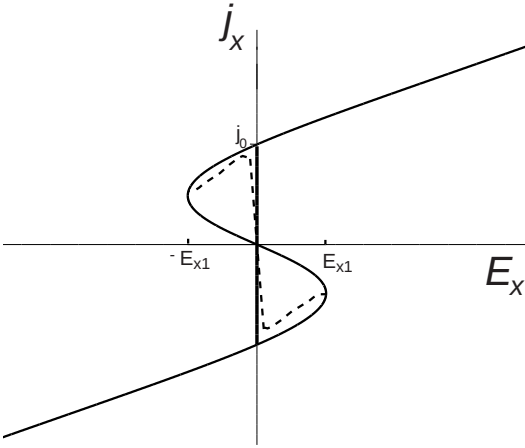


FIG. 3: The S-shaped CVC (solid line) for the case of large magnetic field. Here $\sigma_{min} = \sigma_{max} = 0.1\sigma_H$. The curve intersects the line $E_x = 0$ at the points $j_x = 0, \pm\sigma_H E_0$. The solid vertical line ($E_x = 0, |j_x| < j_0$) corresponds to the stable measurable state on a Hall bar. For a discussion of the dashed line see text.

$-j_0 < j_x < j_0$ (zero resistance state). The part of the $I(V)$ curve with negative conductance can also be measured if one applies short current pulses. The pulsed measurements would allow one to determine a characteristic time required for the build-up of the current filaments. It is worth noting that a switching of the system into a non-homogeneous state has much in common with a first order phase transition (see Ref. [14]). Therefore even in dc measurements it is possible in principle to measure “superheated” and “supercooled” states which correspond to parts of the CVC with negative absolute, but positive differential conductance. As in the case of a first order phase transition, the result of a particular measurement will depend on factors that influence the nucleation of a

new phase (homogeneity of the sample, boundary conditions etc). If the current filament is created in the middle of the sample, the CVC has the form shown in Fig. 3 by the dashed line [14]. This means that the observed CVC may have a hysteresis: with decreasing current it goes along the upper part of the CVC, passes through the intersection point j_0 and reaches a point $j(E_{x1})$. When j_x decreases further, a jump to a curve shown by the dashed line occurs and the CVC follows this line to the region of negative currents. In this configuration, as it is noted in Ref. [5], the current domains (current filaments) with opposite current directions are elongated in the x-direction. The stratification of the current density, as we mentioned above, is natural in systems with S-shaped $I(V)$ characteristic. In the presence of a strong magnetic field the electrical field domains arise simultaneously in the transverse direction (the Hall field domains).

In order to find the form of the electric field and current domains, one needs to derive the full set of equations governing the space and time dependence of all quantities of interest (electric field, current density etc). At present there is no such a theory. Here, we suggest a simple phenomenological model that allows one to map this problem to the problem considered earlier. We assume that the Coulomb screening length is less than the thickness of the 2DEG. In this case the relation between the concentration of electrons n and the electric field $\mathbf{E}$ is given by the Poisson equation

$$\nabla \cdot \mathbf{E} = \frac{4\pi e}{\epsilon} (n - n_0), \quad (4)$$

where n_0 is the electron density in the uniform case. Consider the case of a Corbino disc. Then $E_y = 0$ and the component j_x equals

$$j_x = \sigma(E_x)E_x - eD\partial_x n + \frac{\epsilon}{4\pi}\partial_t E_x. \quad (5)$$

Here the second term is the diffusion current and the third term is the displacement current. This simplified model can not be applied directly to the real experimental situation because it implies a local approximation for the current density, that is, for example the screening length $l_{scr} = \sqrt{D/(4\pi\sigma_{max}/\epsilon)}$ is assumed to be longer than the mean free path (obviously this is not the case in real samples). However this model in our opinion captures the main ingredients of the system qualitatively. One can eliminate the electron density from Eqs. (4) and (5) and obtain for a stationary or steadily moving domain of the electric field

$$\frac{4\pi}{\epsilon}j_x = \frac{4\pi}{\epsilon}\sigma_0(E_x)E_x - D\partial_{\xi}^2 E_x - \partial_{\xi} E_x \left(s - \frac{\sigma_0(E_x)E_x}{en_0} \right). \quad (6)$$

Here $\sigma_0(E_x) = \sigma(E_x)n_0/n$ and $\xi = x - st$. We assumed that $E_x(x, t) = E_x(\xi)$. One can see that Eq. 5 agrees almost completely with an equation describing the Gunn

effect (see [14]). The only difference is that the $\sigma_0(E_x)$ dependence is different in both cases; in particular the symmetry point of the N-shape part of the *CVC* in this case is located at the origin of the coordinates (E_x, j_x) . This means that the topology of solutions in the $(E_x, \partial_\xi E_x)$ plane remains unchanged and therefore many conclusions about *CVC*, forms of the electric field domains in the Gunn effect are valid for our system (however domains in our system are almost motionless). For instance, wide stationary domains with the electric field equal to $\pm E_0$ are described by the phase space trajectory (the separatrix)

$$\frac{1}{r} \left[\mathcal{E}_\zeta - \frac{1}{r} \ln(1 + r\mathcal{E}_\zeta) \right] = U(1) - U(\zeta) \quad (7)$$

where $\zeta = \xi/l_{\text{scr}}$, $r = E_0/(el_{\text{scr}}n_0)$, $\mathcal{E} = E_x/E_0$ is the normalized electric field, $U(\mathcal{E}) = \int_0^\mathcal{E} d\mathcal{E}_1 j(\mathcal{E}_1)/j_m$, $j_m = \sigma_{\text{max}}E_0$, and $j(\mathcal{E}_1) = \sigma(\mathcal{E}_1)\mathcal{E}_1$ is the *CVC*. The screening length l_{scr} in our model determines the width of the domain wall. We will not study here in detail the form of domains arising in the system. Note only that this analysis can be carried out similarly to that presented in Refs. [14, 16].

In summary, we have studied the form of the current-voltage characteristic $I_x(V_x)$ in the presence of non-linearity and magnetic field. The Hall effect removes the distinction between N- and S-shaped *CVC*s characteristic for zero-field systems. Instead the shape of the *CVC* depends on boundary conditions imposed by the experimental setup. We showed that an N-shaped *CVC* in the Corbino disc geometry corresponds for sufficiently strong magnetic fields to an S-shaped *CVC* in the Hall bar geometry. Homogeneous states with negative differential conductivity are unstable to the formation of domains. Again, due to the Hall effect these domains are characterised by both a constant electric field and a constant current density. In these domains the Hall angle is 90 degrees. As a result, we expect the measurements of zero conductance in Corbino discs and zero resistance in Hall bars to be manifestations of the same physical phe-

nomenon.

Note added: After the preparation of this manuscript we became aware of Ref. [17] that reports the observation of an apparently zero-conductance state in a Corbino disc geometry.

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